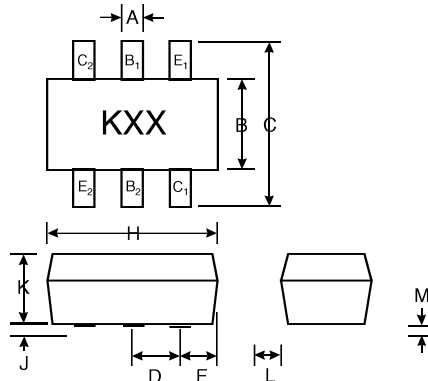


Features

Complementary Pair
Epitaxial Planar Die Construction
Ultra-Small Surface Mount Package
One 2222A-Type NPN,
One 2907A-Type PNP
Ideal for Low Power Amplification and
Switching

Mechanical Data

Case: SOT-363, Molded Plastic
Terminals: Solderable per MIL-STD-202,
Method 208
Terminal Connections: See Diagram
Marking: K27
Weight: 0.006 grams (approx.)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J		0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
All Dimensions in mm		

Note: E1, B1, and C1 = PNP2907A Section,
E2, B2, and C2 = NPN2222A Section.
Type marking indicates orientation.

Maximum Ratings, NPN2222A Section

@ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	NPN2222A	Unit
Collector-Base Voltage	V_{CBO}	75	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current - Continuous (Note 1)	I_C	600	mA
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	R_{JA}	625	K/W
Operating and Storage and Temperature Range	T_J, T_{STG}	-55 to +150	C

Maximum Ratings, PNP2907A Section

@ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	PNP2907A	Unit
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous (Note 1)	I_C	-600	mA
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	R_{JA}	625	K/W
Operating and Storage and Temperature Range	T_J, T_{STG}	-55 to +150	C

Note: 1. Valid provided that terminals are kept at ambient temperature.
2. Pulse test: Pulse width 300 s, duty cycle 2%.

Electrical Characteristics, NPN2222A Section

@ T_A = 25 °C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 2)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	75		V	I _C = 10 A, I _E = 0
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40		V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0		V	I _E = 10 A, I _C = 0
Collector Cutoff Current	I _{CBO}		10	nA A	V _{CB} = 60V, I _E = 0 V _{CB} = 60V, I _E = 0, T _A = 150 °C
Collector Cutoff Current	I _{CEX}		10	nA	V _{CE} = 60V, V _{EB(OFF)} = 3.0V
Emitter Cutoff Current	I _{EBO}		10	nA	V _{EB} = 3.0V, I _C = 0
Base Cutoff Current	I _{BL}		20	nA	V _{CE} = 60V, V _{EB(OFF)} = 3.0V
ON CHARACTERISTICS (Note 2)					
DC Current Gain	h _{FE}	35 50 75 100 40 50 35	300		I _C = 100 A, V _{CE} = 10V I _C = 1.0mA, V _{CE} = 10V I _C = 10mA, V _{CE} = 10V I _C = 150mA, V _{CE} = 10V I _C = 500mA, V _{CE} = 10V I _C = 10mA, V _{CE} = 10V, T _A = -55 °C I _C = 150mA, V _{CE} = 1.0V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.3 1.0	V	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA
Base- Emitter Saturation Voltage	V _{BE(SAT)}	0.6	1.2 2.0	V	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}		8	pF	V _{CB} = 10V, f = 1.0MHz, I _E = 0
Input Capacitance	C _{ibo}	—	25	pF	V _{EB} = 0.5V, f = 1.0MHz, I _C = 0
Current Gain-Bandwidth Product	f _T	300		MHz	V _{CE} = 20V, I _C = 20mA, f = 100MHz
Noise Figure	NF		4.0	dB	V _{CE} = 10V, I _C = 100 A, R _S = 1.0k f = 1.0kHz
SWITCHING CHARACTERISTICS					
Delay Time	t _d		10	ns	V _{CC} = 30V, I _C = 150mA, V _{BE(off)} = - 0.5V, I _{B1} = 15mA
Rise Time	t _r		25	ns	

- Note:
1. Valid provided that terminals are kept at ambient temperature.
 2. Pulse test: Pulse width 300 s, duty cycle 2%.

Electrical Characteristics, PNP2907A Section

@ $T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 2)					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-60		V	$I_C = -10\text{ A}$, $I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-60		V	$I_C = -10\text{mA}$, $I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5.0		V	$I_E = -10\text{ A}$, $I_C = 0$
Collector Cutoff Current	I_{CBO}		-10	nA A	$V_{CB} = -50\text{V}$, $I_E = 0$ $V_{CB} = -50\text{V}$, $I_E = 0$, $T_A = 125\text{ }^{\circ}\text{C}$
Collector Cutoff Current	I_{CEX}		-50	nA	$V_{CE} = -30\text{V}$, $V_{EB(OFF)} = -0.5\text{V}$
Base Cutoff Current	I_{BL}		-50	nA	$V_{CE} = -30\text{V}$, $V_{EB(OFF)} = -0.5\text{V}$
ON CHARACTERISTICS (Note 2)					
DC Current Gain	h_{FE}	75 100 100 100 50	300		$I_C = -100\mu\text{A}$, $V_{CE} = -10\text{V}$ $I_C = -1.0\text{mA}$, $V_{CE} = -10\text{V}$ $I_C = -10\text{mA}$, $V_{CE} = -10\text{V}$ $I_C = -150\text{mA}$, $V_{CE} = -10\text{V}$ $I_C = -500\text{mA}$, $V_{CE} = -10\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$		-0.4 -1.6	V	$I_C = -150\text{mA}$, $I_B = -15\text{mA}$ $I_C = -500\text{mA}$, $I_B = -50\text{mA}$
Base- Emitter Saturation Voltage	$V_{BE(SAT)}$		-1.3 -2.6	V	$I_C = 150\text{mA}$, $I_B = 15\text{mA}$ $I_C = 500\text{mA}$, $I_B = 50\text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}		8.0	pF	$V_{CB} = -10\text{V}$, $f = 1.0\text{MHz}$, $I_E = 0$
Input Capacitance	C_{ibo}	—	30	pF	$V_{EB} = -2.0\text{V}$, $f = 1.0\text{MHz}$, $I_C = 0$
Current Gain-Bandwidth Product	f_T	200		MHz	$V_{CE} = -20\text{V}$, $I_C = -50\text{mA}$, $f = 100\text{MHz}$
SWITCHING CHARACTERISTICS					
Turn-On Time	t_{on}		45	ns	$I_C = -150\text{mA}$, $V_{CC} = -30\text{V}$, $I_{B1} = -15\text{mA}$
Delay Time	t_d		10	ns	$V_{CC} = -30\text{V}$, $I_C = -150\text{mA}$, $I_{B1} = -15\text{mA}$
Rise Time	t_r		40	ns	

- Notes: 1. Valid provided that terminals are kept at ambient temperature.
2. Pulse test: Pulse width 300 μs , duty cycle 2%.